

BR800 - BR810

PRV : 50 - 1000 Volts

Io : 8.0 Amperes

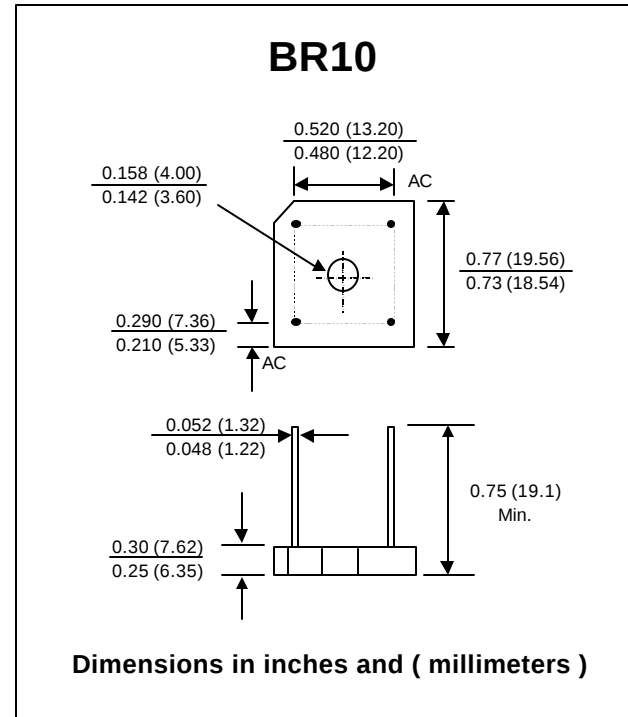
FEATURES :

- * High current capability
- * High surge current capability
- * High reliability
- * Low reverse current
- * Low forward voltage drop
- * Ideal for printed circuit board

MECHANICAL DATA :

- * Case : Reliable low cost construction utilizing molded plastic technique
- * Epoxy : UL94V-O rate flame retardant
- * Lead : Axial lead solderable per MIL - STD 202 , Method 208 guaranteed
- * Polarity : Polarity symbols marked on case
- * Mounting position : Any
- * Weight : 6.1 grams

SILICON BRIDGE RECTIFIERS



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

RATING	SYMBOL	BR800	BR801	BR802	BR804	BR806	BR808	BR810	UNIT
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Current $T_c=50^{\circ}\text{C}$	$I_{F(AV)}$	8.0							Amps.
Peak Forward Surge Current Single half sine wave Superimposed on rated load (JEDEC Method)	I_{FSM}	300							Amps.
Current Squared Time at $t < 8.3$ ms.	$I^2 t$	160							$A^2 S$
Maximum Forward Voltage per Diode at $I_F = 4.0$ Amp.	V_F	1.0							Volts
Maximum DC Reverse Current $T_a = 25^{\circ}\text{C}$	I_R	10							μA
at Rated DC Blocking Voltage $T_a = 100^{\circ}\text{C}$	$I_{R(H)}$	200							μA
Typical Thermal Resistance (Note 1)	$R_{\theta JC}$	2.5							$^{\circ}\text{C/W}$
Operating Junction Temperature Range	T_J	- 40 to + 150							$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	- 40 to + 150							$^{\circ}\text{C}$

Notes :

1. Thermal Resistance from junction to case with units mounted on a 3.2" x 3.2" x 0.12" THK (8.2cm.x 8.2cm.x 0.3cm.) Al. Plate. heatsink.

RATING AND CHARACTERISTIC CURVES (BR800 - BR810)

FIG.1 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

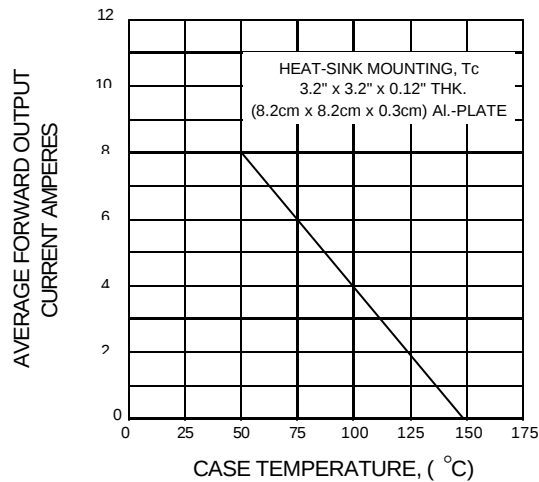


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

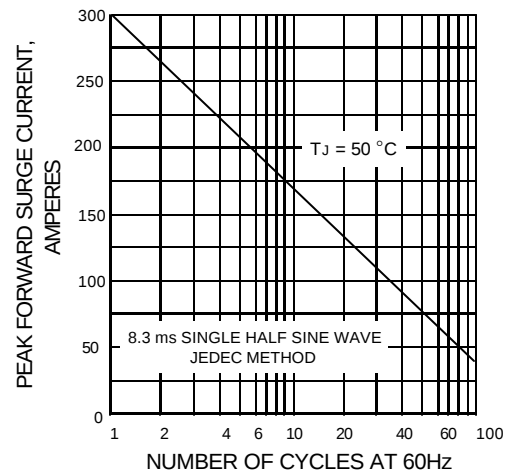


FIG.3 - TYPICAL FORWARD CHARACTERISTICS PER DIODE

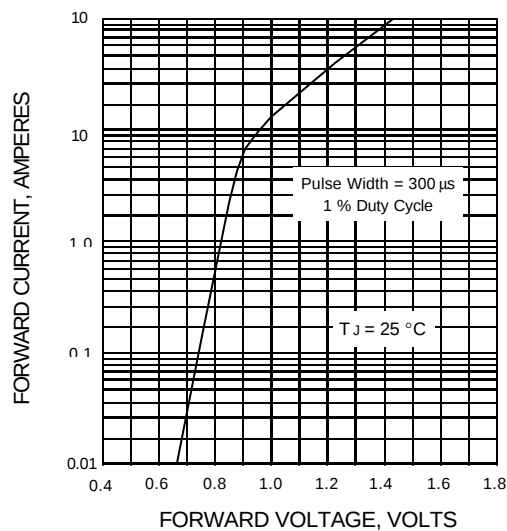


FIG.4 - TYPICAL REVERSE CHARACTERISTICS PER DIODE

